# **ON Semiconductor**

# Is Now



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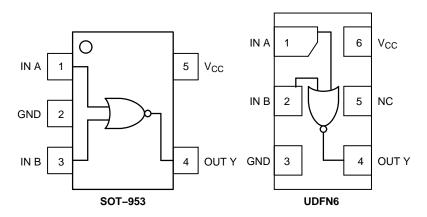
# **Single 2-Input NOR Gate**

The NL17SG02 MiniGate<sup>™</sup> is an advanced high-speed CMOS 2-input NOR gate in ultra-small footprint.

The NL17SG02 input structures provides protection when voltages up to 4.6 V are applied.

#### **Features**

- Wide Operating V<sub>CC</sub> Range: 0.9 V to 3.6 V
- High Speed:  $t_{PD} = 2.4 \text{ ns}$  (Typ) at  $V_{CC} = 3.0 \text{ V}$ ,  $C_L = 15 \text{ pF}$
- Low Power Dissipation:  $I_{CC} = 0.5 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- These are Pb-Free and Halide-Free Devices



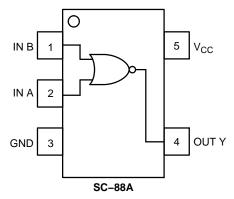


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



#### ON Semiconductor®

http://onsemi.com

#### MARKING DIAGRAMS



SOT-953 CASE 527AE





UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.45 x 1.0 CASE 517AQ





SC-88A DF SUFFIX CASE 419A



M = Date Code\*

■ = Pb–Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or position may vary
depending upon manufacturing location.

#### **PIN ASSIGNMENT**

|   | SOT-953         | SC-88A          | UDFN6           |
|---|-----------------|-----------------|-----------------|
| 1 | IN A            | IN B            | IN A            |
| 2 | GND             | IN A            | IN B            |
| 3 | IN B            | GND             | GND             |
| 4 | OUT Y           | OUT Y           | OUT Y           |
| 5 | V <sub>CC</sub> | V <sub>CC</sub> | NC              |
| 6 |                 |                 | V <sub>CC</sub> |

#### **FUNCTION TABLE**

| Inp | uts | Output |
|-----|-----|--------|
| Α   | В   | Υ      |
| L   | L   | Н      |
| L   | Н   | L      |
| н   | L   | L      |
| Н   | Н   | L      |

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 5 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol               | Parameter                                       | Value  | Unit   |    |
|----------------------|---|--|--|----|
| V <sub>CC</sub>      | DC Supply Voltage                               |  | -0.5 to +5.5                                 | V  |
| V <sub>IN</sub>      | DC Input Voltage                                |  | -0.5 to +4.6                                 | V  |
| V <sub>OUT</sub>     | DC Output Voltage                               | Output at High or Low State<br>Power–Down Mode (V <sub>CC</sub> = 0 V) | -0.5 to V <sub>CC</sub> +0.5<br>-0.5 to +4.6 | V  |
| I <sub>IK</sub>      | DC Input Diode Current                          | V <sub>IN</sub> < GND  | -20  | mA |
| lok                  | DC Output Diode Current                         | V <sub>OUT</sub> < GND   | -20  | mA |
| I <sub>OUT</sub>     | DC Output Source/Sink Current                   |  | ±20  | mA |
| I <sub>CC</sub>      | DC Supply Current per Supply Pin                |  | ±20  | mA |
| I <sub>GND</sub>     | DC Ground Current per Ground Pin                |  | ±20  | mA |
| T <sub>STG</sub>     | Storage Temperature Range                       |  | −65 to +150                                  | °C |
| TL                   | Lead Temperature, 1 mm from Case for 10 Seconds |  | 260  | °C |
| TJ                   | Junction Temperature Under Bias                 |  | +150   | °C |
| MSL                  | Moisture Sensitivity                            |  | Level 1                                      |    |
| F <sub>R</sub>       | Flammability Rating                             | Oxygen Index: 28 to 34   | UL 94 V-0 @ 0.125 in                         |    |
| V <sub>ESD</sub>     | ESD Withstand Voltage                           | Human Body Model (Note 2)<br>Machine Model (Note 3)                    | >2000<br>>100                                | V  |
| I <sub>LATCHUP</sub> | Latchup Performance Above V <sub>CC</sub> an    | d Below GND at 125°C (Note 4)  | ±100   | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

Tested to EIA/JESD22-A114-A.

Tested to EIA/JESD22-A115-A.

- 4. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

| Symbol                | Characteristics  | Min             | Max                    | Unit |
|-----------------------|--|-----------------|------------------------|------|
| V <sub>CC</sub>       | Positive DC Supply Voltage   | 0.9             | 3.6                    | V    |
| $V_{IN}$              | Digital Input Voltage  | 0.0             | 3.6                    | V    |
| V <sub>OUT</sub>      | Output Voltage Output at High or Low State Power–Down Mode ( $V_{CC} = 0 \ V_{CC}$ | e 0.0<br>') 0.0 | V <sub>CC</sub><br>3.6 | V    |
| T <sub>A</sub>        | Operating Temperature Range  | -55             | +125                   | °C   |
| $\Delta t / \Delta V$ | Input Transition Rise or Fail Rate $V_{CC} = 3.3 \text{ V} \pm 0.3$                | V 0             | 10                     | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS

|                 |                             |                                       |                                       | $T_{A} = 25^{\circ}C$ $T_{A} = -55^{\circ}C \text{ to } +125^{\circ}$ |                      |                      |                      |                      |                 |  |   |
|-----------------|-----------------------------|---------------------------------------|---------------------------------------|---|----------------------|----------------------|----------------------|----------------------|-----------------|--|---|
| Symbol          | mbol Parameter              |                                       | onditions                             | V <sub>CC</sub> (V)   | Min                  | Max                  | Max Min              |                      | Unit            |  |   |
| V <sub>IH</sub> |                             |                                       |                                       |   |                      | 0.9                  | V <sub>CC</sub>      |                      | V <sub>CC</sub> |  | V |
|                 | Input<br>Voltage            |                                       |                                       | 1.1 to 1.3  | 0.7xV <sub>CC</sub>  |                      | 0.7xV <sub>CC</sub>  |                      |                 |  |   |
|                 | romago                      |                                       |                                       | 1.4 to 1.6  | 0.65xV <sub>CC</sub> |                      | 0.65xV <sub>CC</sub> |                      |                 |  |   |
|                 |                             |                                       |                                       | 1.65 to 1.95  | 0.65xV <sub>CC</sub> |                      | 0.65xV <sub>CC</sub> |                      |                 |  |   |
|                 |                             |                                       |                                       | 2.3 to 2.7  | 1.7                  |                      | 1.7                  |                      |                 |  |   |
|                 |                             |                                       |                                       | 3.0 to 3.6  | 2.0                  |                      | 2.0                  |                      |                 |  |   |
| V <sub>IL</sub> | Low-Level Input             |                                       |                                       | 0.9   |                      | GND                  |                      | GND                  | V               |  |   |
|                 | Voltage                     |                                       |                                       | 1.1 to 1.3  |                      | 0.3xV <sub>CC</sub>  |                      | 0.3xV <sub>CC</sub>  |                 |  |   |
|                 |                             |                                       |                                       | 1.4 to 1.6  |                      | 0.35xV <sub>CC</sub> |                      | 0.35xV <sub>CC</sub> |                 |  |   |
|                 |                             |                                       |                                       | 1.65 to 1.95  |                      | 0.35xV <sub>CC</sub> |                      | 0.35xV <sub>CC</sub> |                 |  |   |
|                 |                             |                                       |                                       | 2.3 to 2.7  |                      | 0.7                  |                      | 0.7                  |                 |  |   |
|                 |                             |                                       |                                       | 3.0 to 3.6  |                      | 0.8                  |                      | 0.8                  |                 |  |   |
| V <sub>OH</sub> | High-Level                  | V <sub>IN</sub> =                     | $I_{OH} = -20 \mu A$                  | 0.9   | 0.75                 |                      | 0.75                 |                      | V               |  |   |
|                 | Output Voltage              | Output Voltage                        | V <sub>IH</sub> or<br>V <sub>IL</sub> | I <sub>OH</sub> =<br>-0.3 mA  | 1.1 to 1.3           | 0.75xV <sub>CC</sub> |                      | 0.75xV <sub>CC</sub> |                 |  |   |
|                 |                             |                                       | I <sub>OH</sub> =<br>-1.7 mA          | 1.4 to 1.6  | 0.75xV <sub>CC</sub> |                      | 0.75xV <sub>CC</sub> |                      |                 |  |   |
|                 |                             |                                       | I <sub>OH</sub> =<br>-3.0 mA          | 1.65 to 1.95  | Vcc-0.45             |                      | Vcc-0.45             |                      |                 |  |   |
|                 |                             |                                       | I <sub>OH</sub> =<br>-4.0 mA          | 2.3 to 2.7  | 2.0                  |                      | 2.0                  |                      |                 |  |   |
|                 |                             |                                       | I <sub>OH</sub> =<br>-8.0 mA          | 3.0 to 3.6  | 2.48                 |                      | 2.48                 |                      |                 |  |   |
| $V_{OL}$        | Low-Level                   | V <sub>IN</sub> =                     | I <sub>OL</sub> = 20 μA               | 0.9   |                      | 0.1                  |                      | 0.1                  | V               |  |   |
|                 | Output Voltage              | V <sub>IH</sub> or<br>V <sub>IL</sub> | $I_{OL} = 0.3 \text{ mA}$             | 1.1 to 1.3  |                      | 0.25xV <sub>CC</sub> |                      | 0.25xV <sub>CC</sub> |                 |  |   |
|                 |                             |                                       | I <sub>OL</sub> = 1.7 mA              | 1.4 to 1.6  |                      | 0.25xV <sub>CC</sub> |                      | 0.25xV <sub>CC</sub> |                 |  |   |
|                 |                             |                                       | $I_{OL} = 3.0 \text{ mA}$             | 1.65 to 1.95  |                      | 0.45                 |                      | 0.45                 |                 |  |   |
|                 |                             |                                       | $I_{OL} = 4.0 \text{ mA}$             | 2.3 to 2.7  |                      | 0.4                  |                      | 0.4                  |                 |  |   |
|                 |                             |                                       | $I_{OL} = 8.0 \text{ mA}$             | 3.0 to 3.6  |                      | 0.4                  |                      | 0.4                  |                 |  |   |
| I <sub>IN</sub> | Input Leakage<br>Current    | 0 ≤                                   | V <sub>IN</sub> ≤ 3.6 V               | 0 to 3.6  |                      | ±0.1                 |                      | ±1.0                 | μΑ              |  |   |
| I <sub>CC</sub> | Quiescent<br>Supply Current | V <sub>IN</sub> =                     | V <sub>CC</sub> or GND                | 3.6   |                      | 0.5                  |                      | 10.0                 | μΑ              |  |   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### AC ELECTRICAL CHARACTERISTICS Input $t_r = t_f = 3.0 \text{ ns}$

| Symbol             | Parameter                                 | Test Condition                                      | V <sub>CC</sub> (V) | ,          | T <sub>A</sub> = 25° C |      | T⊿<br>–55°C to | , =<br>o +125°C |      |     |   |     |   |
|--------------------|---|---|---------------------|------------|------------------------|------|----------------|-----------------|------|-----|---|-----|---|
| -                  |   |   |                     | Min        | Тур                    | Max  | Min            | Max             | Unit |     |   |     |   |
| t <sub>PLH</sub> , | Propagation Delay,                        | C <sub>L</sub> = 10 pF,                             | 0.9                 | _          | 12.5                   | 14.8 | _              | 16.0            | ns   |     |   |     |   |
| t <sub>PHL</sub>   | A or B to Y                               | $R_L = 1 M\Omega$                                   | 1.1 to 1.3          | -          | 8.8                    | 11.4 | -              | 13.2            |      |     |   |     |   |
|                    |   |   | 1.4 to 1.6          | _          | 5.0                    | 8.5  | -              | 10.0            |      |     |   |     |   |
|                    |   |   | 1.65 to 1.95        | _          | 3.8                    | 6.2  | -              | 6.7             |      |     |   |     |   |
|                    |   |   | 2.3 to 2.7          | _          | 2.7                    | 3.9  | -              | 4.4             |      |     |   |     |   |
|                    |   |   | 3.0 to 3.6          | -          | 2.1                    | 3.1  | -              | 3.7             |      |     |   |     |   |
|                    |   | $C_L = 15 \text{ pF},$<br>$R_L = 1 \text{ M}\Omega$ | 0.9                 | _          | 13.7                   | 15.5 | -              | 17.3            | ns   |     |   |     |   |
|                    |   | K <sup>L</sup> = 1 M22                              | 1.1 to 1.3          | _          | 10.6                   | 12.5 | -              | 15.2            |      |     |   |     |   |
|                    |   |   | 1.4 to 1.6          | -          | 5.9                    | 9.3  | -              | 11.2            |      |     |   |     |   |
|                    |   |   | 1.65 to 1.95        | _          | 4.5                    | 6.9  | _              | 7.1             |      |     |   |     |   |
|                    |   |   |                     |            |                        |      | 2.3 to 2.7     | _               | 3.0  | 4.4 | _ | 5.0 | ] |
|                    |   |   |                     | 3.0 to 3.6 | _                      | 2.4  | 3.4            | _               | 3.9  |     |   |     |   |
|                    |   | $C_L = 30 \text{ pF},$<br>$R_L = 1 \text{ M}\Omega$ | 0.9                 | _          | 15.5                   | 17.6 | -              | 20.3            | ns   |     |   |     |   |
|                    |   | KL = 1 IVIS2  | 1.1 to 1.3          | _          | 11.8                   | 14.6 | -              | 17.0            | ]    |     |   |     |   |
|                    |   |   | 1.4 to 1.6          | _          | 8.0                    | 13.1 | -              | 15.9            |      |     |   |     |   |
|                    |   |   | _                   | 6.0        | 9.2                    | -    | 9.6            | ]               |      |     |   |     |   |
|                    |   |   | 2.3 to 2.7 –        | _          | 3.9                    | 5.7  | -              | 6.1             |      |     |   |     |   |
|                    |   |   | 3.0 to 3.6          | -          | 3.0                    | 4.4  | -              | 4.8             |      |     |   |     |   |
| C <sub>IN</sub>    | Input Capacitance                         |   | 0 to 3.6            |            | 3                      | -    | _              | -               | pF   |     |   |     |   |
| C <sub>PD</sub>    | Power Dissipation<br>Capacitance (Note 5) | f = 10 MHz  | 0.9 to 3.6          | _          | 4                      | -    | -              | _               | pF   |     |   |     |   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC} \cdot C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

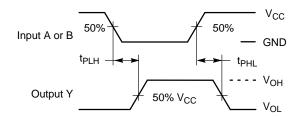
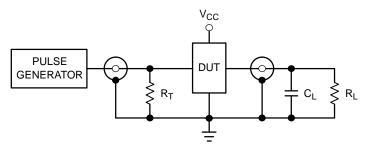


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

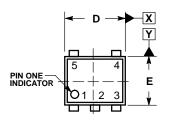
#### **ORDERING INFORMATION**

| Device          | Package                      | Shipping <sup>†</sup> |
|-----------------|------------------------------|-----------------------|
| NL17SG02P5T5G   | SOT-953<br>(Pb-Free)         | 8000 / Tape & Reel    |
| NL17SG02DFT2G   | SC-88A<br>(Pb-Free)          | 3000 / Tape & Reel    |
| NL17SG02AMUTCG  | UDFN6 1.45x1 mm<br>(Pb-Free) | 3000 / Tape & Reel    |
| NL17SG02CMUTCG* | UDFN6 1x1 mm<br>(Pb–Free)    | 3000 / Tape & Reel    |

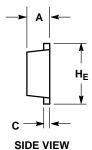
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. \*In Development.

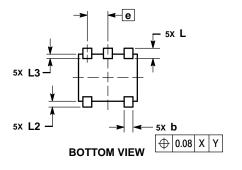
#### **PACKAGE DIMENSIONS**

#### SOT-953 CASE 527AE ISSUE E



**TOP VIEW** 





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

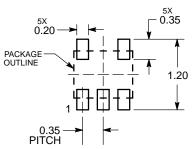
  2. CONTROLLING DIMENSION: MILLIMETERS

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | MILLIMETERS |         |      |  |  |  |
|-----|-------------|---------|------|--|--|--|
| DIM | MIN NOM MAX |         |      |  |  |  |
| Α   | 0.34        | 0.37    | 0.40 |  |  |  |
| b   | 0.10        | 0.15    | 0.20 |  |  |  |
| С   | 0.07        | 0.12    | 0.17 |  |  |  |
| D   | 0.95        | 1.00    | 1.05 |  |  |  |
| Е   | 0.75        | 0.80    | 0.85 |  |  |  |
| е   |             | 0.35 BS | С    |  |  |  |
| HE  | 0.95        | 1.00    | 1.05 |  |  |  |
| L   | 0.175 REF   |         |      |  |  |  |
| L2  | 0.05        | 0.10    | 0.15 |  |  |  |
| L3  |             |         | 0.15 |  |  |  |

#### **SOLDERING FOOTPRINT\***

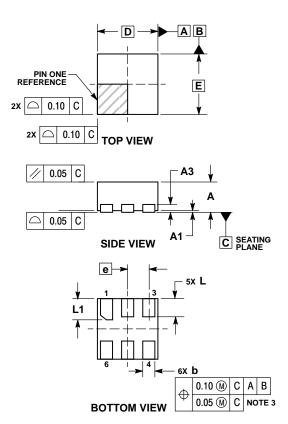


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

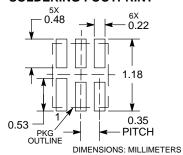
UDFN6 1.0x1.0, 0.35P CASE 517BX **ISSUE O** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

|     | MILLIMETERS |      |  |  |  |  |
|-----|-------------|------|--|--|--|--|
| DIM | MIN         | MAX  |  |  |  |  |
| Α   | 0.45        | 0.55 |  |  |  |  |
| A1  | 0.00        | 0.05 |  |  |  |  |
| А3  | 0.13 REF    |      |  |  |  |  |
| b   | 0.12        | 0.22 |  |  |  |  |
| D   | 1.00        | BSC  |  |  |  |  |
| Е   | 1.00        | BSC  |  |  |  |  |
| е   | 0.35 BSC    |      |  |  |  |  |
| L   | 0.25        | 0.35 |  |  |  |  |
| 11  | 0.30        | 0.40 |  |  |  |  |

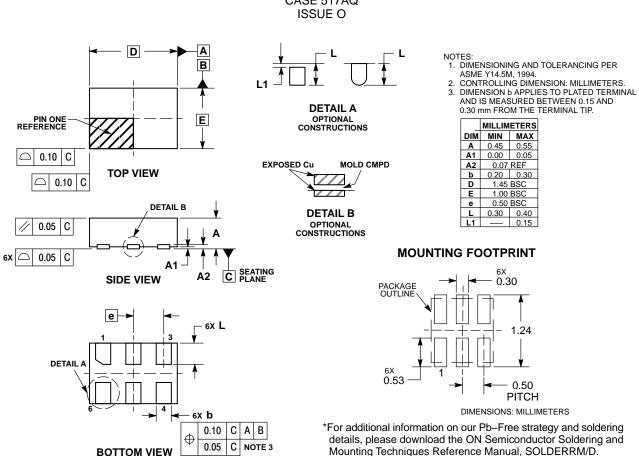
#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

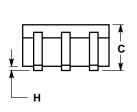
#### **PACKAGE DIMENSIONS**

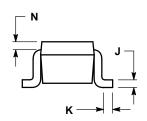
## UDFN6 1.45x1.0, 0.5P CASE 517AQ



#### PACKAGE DIMENSIONS

# 



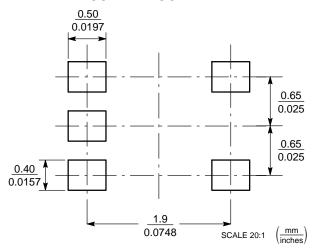


#### NOTES:

- DIMENSIONING AND TOLERANCING
   PER ANSI Y14 5M 1982
- PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
- 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
- 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | INC     | HES   | MILLIN   | IETERS |  |
|-----|---------|-------|----------|--------|--|
| DIM | MIN MAX |       | MIN      | MAX    |  |
| Α   | 0.071   | 0.087 | 1.80     | 2.20   |  |
| В   | 0.045   | 0.053 | 1.15     | 1.35   |  |
| C   | 0.031   | 0.043 | 0.80     | 1.10   |  |
| D   | 0.004   | 0.012 | 0.10     | 0.30   |  |
| G   | 0.026   | BSC   | 0.65 BSC |        |  |
| Н   |         | 0.004 |          | 0.10   |  |
| J   | 0.004   | 0.010 | 0.10     | 0.25   |  |
| K   | 0.004   | 0.012 | 0.10     | 0.30   |  |
| N   | 0.008   | REF   | 0.20     | REF    |  |
| S   | 0.079   | 0.087 | 2.00     | 2.20   |  |

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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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